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Thyristor Surface Mount, Phase Control SCR, 16 A



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D ² PAK	TI O	-മറാ	ADI

PRIMARY CHARACTERISTICS							
I _{T(AV)}	16 A						
V _{DRM} /V _{RRM}	1600 V						
V_{TM}	1.25 V						
I _{GT}	45 mA						
T _J	-40 to +125 °C						
Package	D ² PAK (TO-263AB)						
Circuit configuration	Single SCR						

FEATURES

 Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



 Designed and qualified according JEDEC®-JESD 47

 Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Input rectification (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-25TTS16S-M3 of silicon controlled rectifiers is specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS									
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS									
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz. (140 µm) copper	3.5	5.5							
Aluminum IMS, R _{thCA} = 15 °C/W	8.5	13.5	А						
Aluminum IMS with heatsink, R _{thCA} = 5 °C/W	16.5	25.0							

Note

• $T_A = 55$ °C, $T_J = 125$ °C, footprint 300 mm²

MAJOR RATINGS AND CHARACTERISTICS									
PARAMETER	TEST CONDITIONS	VALUES	UNITS						
I _{T(AV)}	Sinusoidal waveform	16	۸						
I _{RMS}		25	А						
V _{RRM} /V _{DRM}		1600	V						
I _{TSM}		350	А						
V_{T}	16 A, T _J = 25 °C	1.25	V						
dV/dt		500	V/µs						
dl/dt		150	A/µs						
T _J		-40 to +125	°C						

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} , AT 125 °C mA					
VS-25TTS16S-M3	1600	1600	10					



ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEC	T CONDITIONS	VAL	UNITS				
PARAMETER	STINIBUL	SYMBOL TEST CONDITIONS		TYP.	UNITS				
Maximum average on-state current	I _{T(AV)}	T _C = 93 °C, 180° co	1	6					
Maximum RMS on-state current	I _{RMS}			2	5	А			
Maximum peak, one-cycle,	ı	10 ms sine pulse, rated V _{RRM} applied		30	00	A			
non-repetitive surge current	I _{TSM}	10 ms sine pulse, r	3	50					
Maximum 12t for fusing	l ² t	10 ms sine pulse, r	ated V _{RRM} applied	450		A ² s			
Maximum I ² t for fusing	1-1	10 ms sine pulse, r	630		A-S				
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms	s, no voltage reapplied	6300		A²√s			
Maximum on-state voltage drop	V_{TM}	16 A, T _J = 25 °C		1.25		V			
On-state slope resistance	r _t	T 105 °C		12.0		mΩ			
Threshold voltage	V _{T(TO)}	T _J = 125 °C		1.0		V			
Maximum rayaraa and direct lookage current	1 /1	T _J = 25 °C	\/ - ratad \/ \ \/	0	.5				
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	$V_R = \text{rated } V_{RRM} / V_{DRM}$	10					
Holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		-	150	mA			
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T _J = 25 °C			00				
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max., linear}$	to 80 %, V _{DRM} = R _g - k = open	50	00	V/µs			
Maximum rate of rise of turned-on current	dl/dt		-	150		A/µs			

TRIGGERING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum peak gate power	P _{GM}		8.0	W				
Maximum average gate power	P _{G(AV)}		2.0	VV				
Maximum peak positive gate current	+ I _{GM}		1.5	Α				
Maximum peak negative gate voltage	- V _{GM}		10	V				
		Anode supply = 6 V, resistive load, T _J = -10 °C	60	mA				
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	45					
		Anode supply = 6 V, resistive load, T _J = 125 °C	20					
		Anode supply = 6 V, resistive load, T _J = -10 °C	2.5					
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C 2.0] _v				
		Anode supply = 6 V, resistive load, T _J = 125 °C	1.0	v				
Maximum DC gate voltage not to trigger	V_{GD}	T 105 °C V reted value	0.25					
Maximum DC gate current not to trigger	I _{GD}	$T_J = 125 ^{\circ}\text{C}, V_{DRM} = \text{rated value}$	2.0	mA				

SWITCHING								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9					
Typical reverse recovery time	t _{rr}	T _{.1} = 125 °C	4	μs				
Typical turn-off time	t _q	1j = 125 C	110					

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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-40 to +125	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.1	°C/W				
Typical thermal resistance, junction to ambient (PCB mount)	R _{thJA} ⁽¹⁾		40	C/VV				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Marking device		Case style D ² PAK (TO-263AB)	25TT	S16S				

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm] copper 40 °C/W. For recommended footprint and soldering techniques refer to application note #AN-994

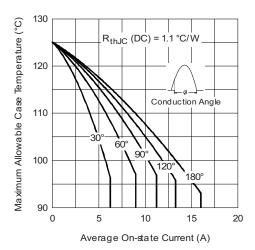


Fig. 1 - Current Rating Characteristics

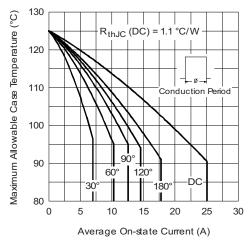


Fig. 2 - Current Rating Characteristics

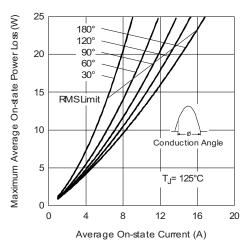


Fig. 3 - On-State Power Loss Characteristics

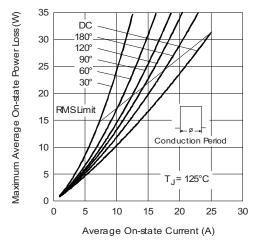


Fig. 4 - On-State Power Loss Characteristics

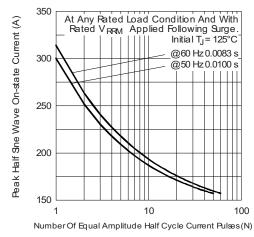


Fig. 5 - Maximum Non-Repetitive Surge Current

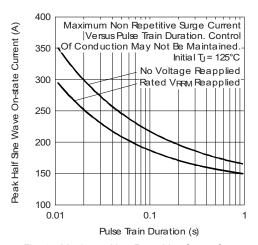


Fig. 6 - Maximum Non-Repetitive Surge Current

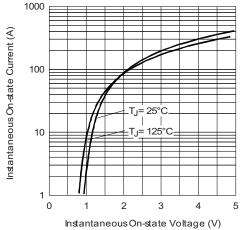


Fig. 7 - On-State Voltage Drop Characteristics

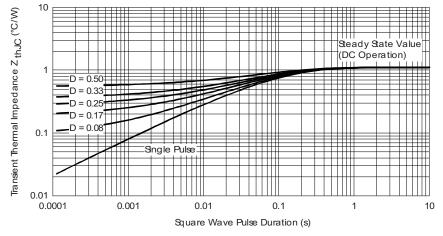


Fig. 8 - Gate Characteristics

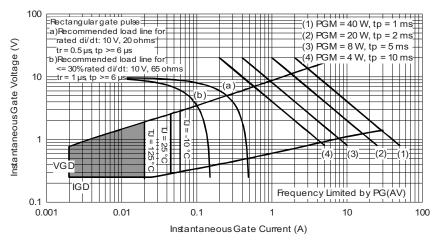


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code VS-S S **TRL** 25 Т Т 16 -M3 (7)(2)(3) (4) (5) (6) (8) 9 Vishay Semiconductors product Current rating (25 = 25 A) Circuit configuration: T = single thyristor Package: $T = D^2PAK (TO-263AB)$ Type of silicon: S = standard recovery rectifier 16 = 1600 V Voltage rating: Voltage code x $100 = V_{RRM}$ S = surface mountable • None = tube • TRL = tape and reel (left oriented) • TRR = tape and reel (right oriented) 9 -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-25TTS16S-M3	50	1000	Antistatic plastic tubes					
VS-25TTS16STRR-M3	800	800	13" diameter reel					
VS-25TTS16STRL-M3	800	800	13" diameter reel					

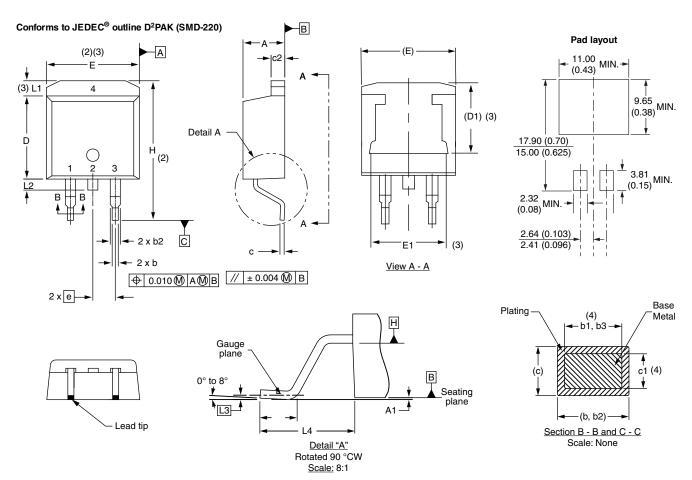
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96164				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96424				

Revision: 04-Jan-18 5 Document Number: 96415



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES	NOTES	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

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